查询SN75LBC784供应商

捷多邦,专业PCB打样工厂,24小时加急出SN75LBC784 QUADRUPLE RS-423-B DRIVER/RECEIVER

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- Four Independent Drivers and Receivers
- Driver Slew Rate Controlled by a Single Resistor
- Fast Driver Transition Times Down to 1.5 μs and Receiver Transition Times of 20 ns Typ
- Internal Thermal-Overload Protection
- RS-423-B Inputs and Outputs Designed to Withstand ±25 V
- ESD Protection Exceeds 2000 V Per MIL-STD-833C Method 3015

● LinBICMOS[™] Process Technology

description

The SN75LBC784 performs as four independent RS-423-B driver/receiver pairs designed to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE) at rates up to 120 kbps and distances to 1.2 km. The SN75LBC784 provides an upgrade to the RS-232 serial interface and can be backward compatible with existing serial ports while offering the higher performance required by new faster peripherals, such as v.34 (v.fast) modems. The RS-232 standard, and subsequent revisions, only support data rates up to 20 kbps over about 15 meters of cable. For RS-423-B the data rate is increased to 120 kbps and transmission distance to 1.2 km by reducing the maximum output signal swing, increasing the driver output current, and reducing the receiver input voltage thresholds.

DW PACKAGE (TOP VIEW)				
3A [1 28 3Z [2 27 BIAS [3 26 4A [4 25 4Z [5 24 BIAS [6 23 V _{SS} [7 22 GND [8 21 4B [9 20 4Y [10 19 3B [11 18 3Y [12 17 3C [13 16 4C [14 15	2Z 2A 3 BIAS 1 Z 1 A 4 R _{ws} 7 V _{DD} 7 1Y 1 B 2 2Y 2 2B 2 2C			
FUNCTION T	- ABLE			
INPUTS	OUTPUTS			
A B C	Z Y			
L L H H L H L H L H H L	H H H L L H L L			
$ \begin{array}{ccccc} L & L & L \\ H & L & L \\ L & H & H \\ H & H & H \\ H = high level, L = low \end{array} $? H ? H ? L			

X = irrelevant, Z = high impedance (off)

? = indeterminate

The receiver input voltage thresholds. The receivers consist of differential comparators with hysteresis and resistive attenuation on the inputs. The resistive attenuation improves the input common mode range and also provides additional protection from ESD and over-voltage stress. The differential and common mode input impedances are sufficiently high to meet RS-423-B. When a differential voltage input of 500 mV is applied across the entire common mode range (see

Figure 5), the receiver characteristics and bias voltage allow the receiver to remain in its intended binary state.

The drivers meet all RS-423-B specifications with built-in current limits and thermal-overload protection. Slew-rate controlling circuitry is included in the design, which is adjusted to suit the application by means of an external resistor (R_{ws}). The slew rate controlling circuitry also has a default mode – if the R_{ws} pin is shorted to 5 V externally, the transistion time defaults to approximately 1.5 ms. The BIAS input, when shorted to 5 V externally, provides the internal node voltages. The receiver is compatible to RS-232 with the use of external input resistors to meet the RS-232 input resistance specification of 3 k Ω to 7 k Ω .

The SN75LBC784 is characterized for operation over the temperature range of 0°C to 70°C.



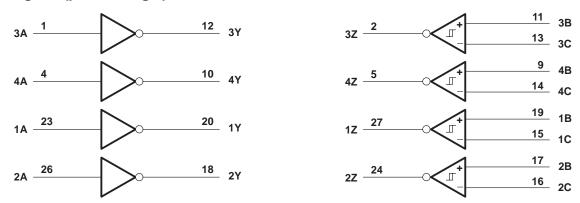
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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Positive supply voltage, V _{DD} (see Note 1)	
Negative supply voltage, V _{SS}	
Bias voltage, V _{bias}	
Receiver input voltage range	
Driver input voltage range	0.5 V to 5.75 V
Driver output voltage range (supplies at 0 V)	
Driver output voltage range (supplies at ±12 V)	
Continuous power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range	
Case temperature for 10 seconds	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
 NOTE 1: All voltages are with respect to network ground terminal.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR [†] ABOVE T _A = 25°C	T _A = 70°C POWER RATING
DW	1348 mW	10.8 mW/°C	862 mW
+			

[†] Derating factors are the inverse of the junction-to-ambient thermal resistance when board-mounted with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, VDD		10.8	12	13.2	V
Supply voltage, VSS		-10.8	-12	-13.2	V
Bias voltage, V _{bias}		2	5	5.5	V
High-level input voltage, VIH	Driver	2			V
Low-level input voltage, VIL	Driver			0.8	V
High-level output current, IOH	Receiver			-4	mA
Low-level output current, IOL	Receiver			4	mA
Rws slew rate control resistor		20	82	820	kΩ
Operating free-air temperature, T_A		0		70	°C



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DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature, V_{DD} = 10.8 V to 13.2 V, V_{SS} = -10.8 V to -13.2 V, T_A = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT
VOH	High-level output voltage	Open circuit or R _L = 4	-50 Ω	4	5.5	6	V
VOL	Low-level output voltage	Open circuit or RL = 4	-50 Ω	-6	-5.5	-4	V
IIH	High-level input current	V _I = 2.4 V to 5.5 V				100	μA
۱ _{IL}	Low-level input current	V _I = 0 V to 0.8 V		-100			μA
lo	Output leakage current	$V_{DD} = V_{SS} = 0,$	$V_{O} = \pm 6 V$	-100		100	μΑ
IOS(H)	High-level short circuit output current	V _I = 5 V,	VO = 0	15		45	mA
IOS(L)	Low-level short circuit output current	$V_{I} = 0,$	VO = 0	-45		-15	mA
1	Supply current	No load			10	12	mA
IDD	Supply current	R _L = 450 Ω			60	70	mA
	Supply current	No load			-10	-12	mA
ISS	Supply current	R _L = 450 Ω			-60	-70	ША
I _{bias}	Bias current					400	μA

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, V_{DD} = 10.8 V to 13.2 V, V_{SS} = -10.8 V to -13.2 V, T_A = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT
	t _{TLH} Transition time, low-to-high level (see Figure 1)		$R_{WS} = 0 \ k\Omega$		1.5		
		$R_{WS} = 20 \ k\Omega$	1.5	2.1	2.7		
t _{TLH}		1	$R_{WS} = 82 \text{ k}\Omega$	5	8	11	μs
		$R_{WS} = 820 \text{ k}\Omega$		80			
			$R_{WS} = 0 \ k\Omega$		1.5		
		$V_{WS} = 5 V$	$R_{WS} = 20 \ k\Omega$	1.5	2.1	2.7	
t _{THL}	Transition time, high-to-low level (see Figure 1)		$R_{WS} = 82 \text{ k}\Omega$	5	8	11	μs
			R _{WS} = 820 kΩ		80		
SR	Output slew rate		Rws = 20 kΩ			15	V/µs
t _{sk}	Output skew (see Figure 4) tPHL - tPLH		$R_{WS} = 82 \ k\Omega$			1	μs



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RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature, V_{DD} = 10.8 V to 13.2 V, V_{SS} = -10.8 V to -13.2 V, T_A = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
\/	Desitive input threshold veltage					200	mV
VIT+	Positive input threshold voltage	With 500 Ω series resi	With 500 Ω series resistor			400	mv
V	Negative input threshold voltage					-200	m\/
V _{IT}	Negative input threshold voltage	With 500 Ω series resi	stor			-400	mV
1.	lanut ourroat	V _I = 10 V	Other input to CND		1.3	3.25	
łı	Input current	$V_{I} = -10 V$	Other input to GND	-3.25	-1.3		mA
V _{hys}	Hysteresis (V _{IT+} – V _{IT} _)			20	40	150	mV
Varia	Lligh lovel output voltage (and Note 2)	I _O = -20 μA	I _O = -20 μA			5	V
VOH	High-level output voltage (see Note 2)	$I_{O} = -4 \text{ mA}$		2.4		5	v
VOL	Low-level output voltage	$I_{O} = 20 \ \mu A \text{ to } 4 \ m A$				0.4	V
I _{RX}	RX short circuit current					50	mA
V _{ID}	Differential input voltage	Receiver inputs open circuit		1.6	2.1	2.6	V
Vofs	Fail safe output voltage	See Note 3		3.5			V

NOTES: 2. Device has an internal RX supply regulator. Maximum RX logic output voltage under no load is thus defined by an internal voltage value. This is nominally set to 4.5 V with a tolerance of ±5%.

3. One input at ground, other input open circuit, $I_0 = -20 \mu A$, or both open circuit.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

test conditions: V_{DD} = 10.8 V to 13.2 V, V_{SS} = -10.8 V to -13.2 V, T_A = 0°C to 70°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	NOM	MAX	UNIT	
t _{PLH}	Propagation Delay time low-to-high (see Figure 2)	С _L = 50 рF			0.15	4	
^t PHL	Propagation delay time high-to-low (see Figure 2)			0.15		μs	
t _{THL}	Transition time high-to-low (see Figure 3)			20	200	ns	
^t TLH	Transition time low-to-high (see Figure 3)			20	200	115	



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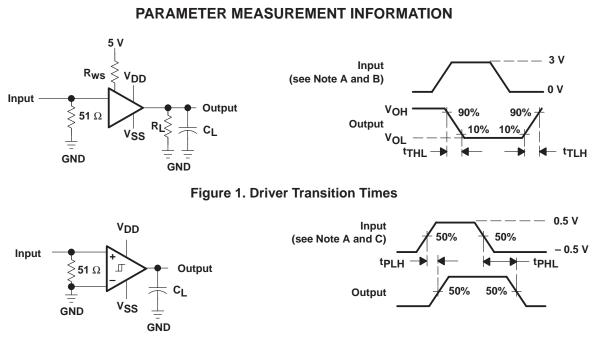
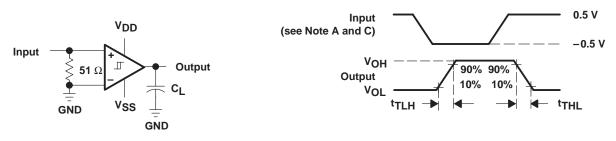


Figure 2. Receiver Propagation Delay Times

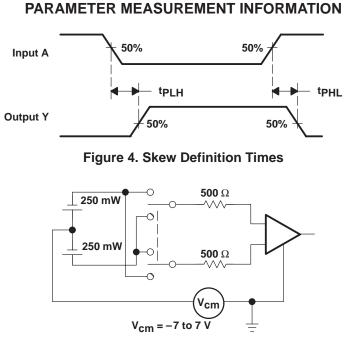


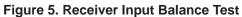


- NOTES: A. C_L includes probe and jig capacitance.
 - B. The input pulse is supplied by a generator having the following characteristics: $t_f \le 10 \text{ nS}$, $t_f < 10 \text{ nS}$, $Z_0 = 50 \Omega$, PRR $\ge 5 \text{ kHz}$, duty cycle 50%, $V_{max} = 3 \text{ V}$, $V_{min} = 0 \text{ V}$.
 - C. The input pulse is supplied by a generator having the following characteristics: $t_r \le 10$ nS, $t_f < 10$ nS, $Z_0 = 50 \Omega$, PRR ≥ 5 kHz, duty cycle 50%, $V_{max} = 0.5$ V, $V_{min} = -0.5$ V.



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